NSN 5961-01-014-9651

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-9651 **Inclosure Material:** Metal or plastic **Overall Length:** 0.785 inches **Overall Height:** 0.180 inches **Overall Width:** 0.250 inches **Component Name And Quantity:** 7 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current outside diameter all semiconductor device diode **Power Rating Per Characteristic:** 1.4 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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